

# A simple model for the prediction of the quench point in cable-in-conduit conductors

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# **General Frame**

DC experiments (runs)

Current Sharing, CS

Critical Current, CC

CS run: fixed operating current, variable He temperature

CC run: fixed He temperature, variable operating current

Power-law conductor

$$E\left(I_{op}, T_{cond}, n
ight) = E_{c} \left(rac{I_{op}}{I_{c}\left(T_{cond}
ight)}
ight)^{n}$$

Critical current scaling by Sommers

Reference conductor CondA (SECRETS & CONDOPT)



# **Thermal Equilibrium**

1<sup>st</sup> Fact: CS and CC runs are steady state

•Temperature (CS) or current (CC) vary so slowly that at each instant of time the conductor and He are in thermal equilibrium

•The VTC or VAC are reversible

2<sup>nd</sup> Fact: The thermal equilibrium is broken at a certain location in the conductor indicating by

•the lost of reversibility

•accelerated increase of voltage and helium temperature

One speaks of: take-off or quench



# Process

#### Two competitive effects:

Power generated in the conductor controlled by operating current and conductor temperature

$$W(I_{op}, T_{cond}, n) = E(I_{op}, T_{cond})I_{op}$$

•Change in  $I_c$  due to the Lorenz laoading

•Change of n with T and B

•Current redistribution

Cooling power controlled by heat exchange coefficient and temperature difference between He and conductor

$$G\left(T_{cond}, T_{He}, h\right) = hp_{w}\left(T_{cond} - T_{He}\right)$$

•Change in h due to Lorenz compaction

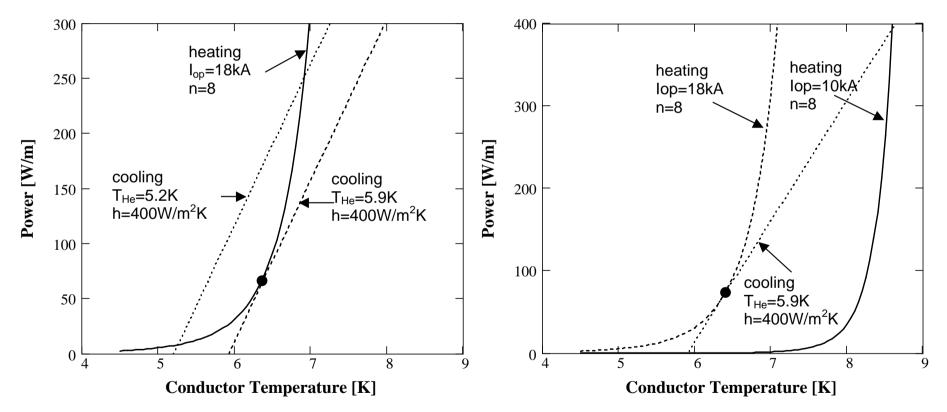
•Local variation of h due to cable geometry



# **Graphical Method**

#### Current sharing

#### Critical current

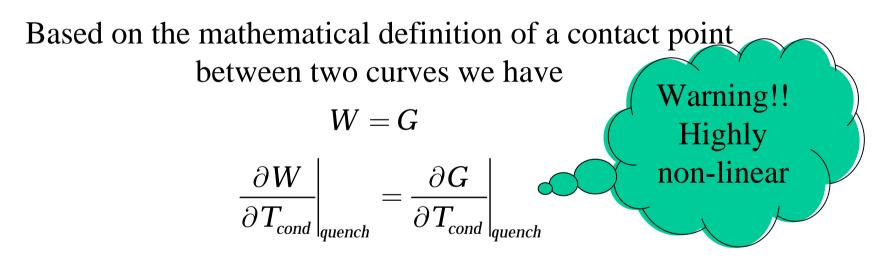


The equation W=G has two solutions. A stable and an unstable one. Both converge to a unique point which is the contact point between the cooling and heating curves. Increasing  $T_{cond}$  beyond this point results in a breakdown of thermal equilibrium between conductor and helium. We have QUENCH



# **The Quench Point**

We saw from the previous analysis that the quench point can be defined as the contact point between the heating and cooling power curves with the conductor temperature as a variable.



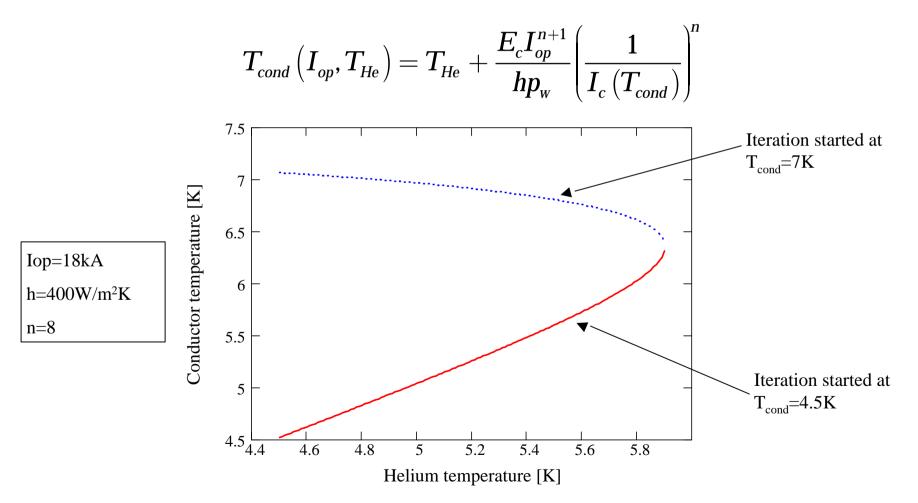
Depending on how you pick the parameters, the output is

$$\begin{split} I_{q} &= f\left(.\left|T_{op}\right) & T_{q_{-}He} = f\left(.\left|I_{op}\right)\right. \\ T_{q_{-}cond} &= f\left(.\left|T_{op}\right.\right) & \text{Or} & T_{q_{-}cond} = f\left(.\left|I_{op}\right.\right) \end{split}$$



# **A Simpler Method**

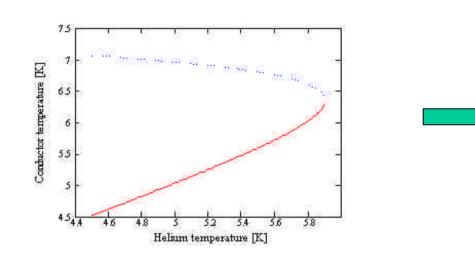
If you do not like derivatives (numerically any way not recommended) just take the first equation G=W but keep Sommers scaling (and any other non-linear stuff)

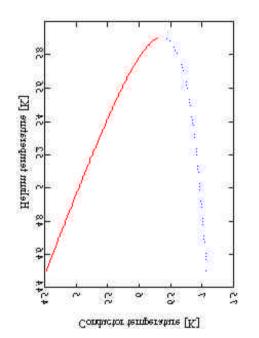




#### **Avoid Convergence Problems**

Rotate by  $90^{\circ}$  and fold





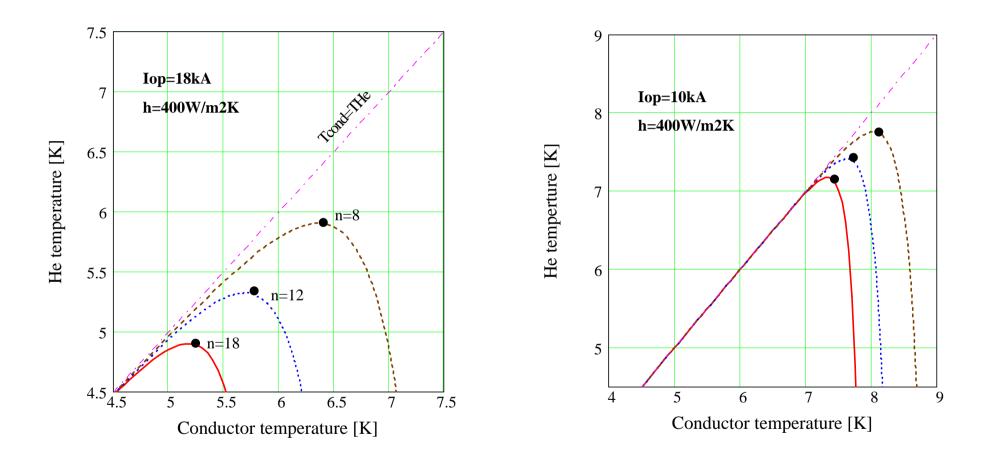
Now the quench point apears as the maximum of the function

$$T_{He}\left(I_{op}, T_{cond}\right) = T_{cond} - \frac{E_{c}I_{op}^{n+1}}{hp_{w}} \left(\frac{1}{I_{c}\left(T_{cond}\right)}\right)^{n}$$

Everything is a matter of finding the maximum of a function



#### **Effect of changing n and operating current**



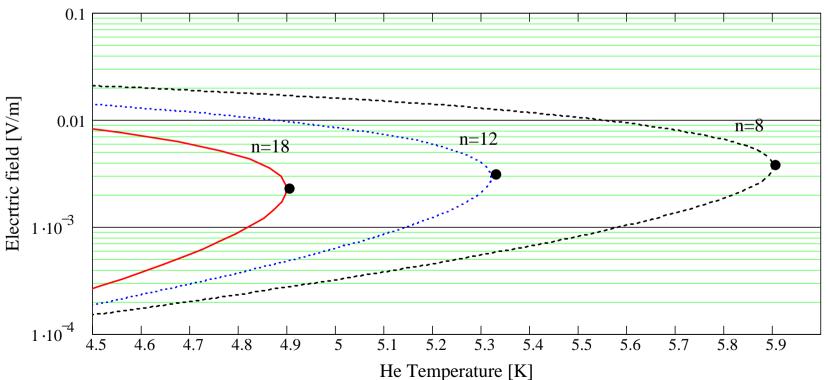


## Effect of changing n on the electric field at quench

Once  $T_{q\_cond}$  and  $I_q$  (or Iop for CS) are known  $E_q$  can be calculated with

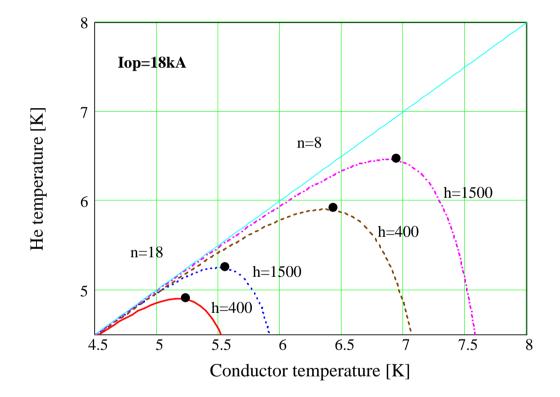
n

$$E_{q} = E_{c} \left( rac{I_{q}}{I_{c} \left( T_{q\_cond} 
ight)} 
ight)$$





## **Effect of heat exchange**





# **Going Analytic**

We learned that the basic equations defining the quench point are:

$$\begin{split} T_{He}\left(I_{op},T_{cond}\right) &= T_{cond} - \frac{E_{c}I_{op}^{n+1}}{hp_{w}} \left(\frac{1}{I_{c}\left(T_{cond}\right)}\right)^{n} \\ &\frac{\partial T_{He}}{\partial T_{cond}} = \mathbf{0} \end{split}$$

The second equation selects the maximum of  $T_{He}(T_{cond})$  and if we neglect the temperature dependence of n

$$1 - \frac{nE_c}{hp_w} \left(\frac{I}{I_c}\right)^{n+1} \left|\frac{\partial I_c}{\partial T_{cond}}\right| = 0$$

Everything is manageable analyticaly

But if 
$$I_c(T_{cond}) = I_{c0} \left( 1 - \frac{T_{cond}}{T_c} \right)$$
 manages analytics



# **A Collection of Analytical Results**

$$T_{q_{-}cond} = T_{c} \left[ 1 - \frac{I_{q}}{I_{c0}} \left( \frac{nE_{c}I_{c0}}{hp_{w}T_{c}} \right)^{\frac{1}{n+1}} \right]$$

$$T_{q_{-}He} = T_{c} \left[ 1 - \frac{n+1}{n} \frac{I_{q}}{I_{c0}} \left( \frac{nE_{c}I_{c0}}{hp_{w}T_{c}} \right)^{\frac{1}{n+1}} \right]$$

$$T_{q\_cond} = \left(\frac{n}{n+1}\right) T_{q\_He} + \frac{T_c}{n+1}$$
 Linear relation !

$$\Phi = \frac{hp_w T_c}{E_c I_{c0}}$$
 Non-dimensional group:  
Quench number ?

$$\begin{split} T_{q_{-}He} &= T_{c} \left( 1 - \frac{n+1}{n} \frac{I_{q}}{I_{c0}} \frac{1}{\left(\frac{\Phi}{n}\right)^{\frac{1}{n+1}}} \right) \\ T_{q_{-}cond} &= T_{c} \left( 1 - \frac{I_{q}}{I_{c0}} \frac{1}{\left(\frac{\Phi}{n}\right)^{\frac{1}{n+1}}} \right) \end{split}$$

$$E_q = E_c \left(\frac{\Phi}{n}\right)^{\frac{n}{n+1}}$$

$$E_q = E_c \left(\frac{hp_w T_c}{nE_c I_{c0}}\right)^{\frac{n}{n+1}}$$



### How to use Formulas

$$\begin{aligned} & Current sharing\\ T_{q_-He} = T_c \left( 1 - \frac{n+1}{n} \frac{I_{op}}{I_{c0}} \frac{1}{\left(\frac{\Phi}{n}\right)^{\frac{1}{n+1}}} \right)\\ & T_{q_-cond} = T_c \left( 1 - \frac{I_{op}}{I_{c0}} \frac{1}{\left(\frac{\Phi}{n}\right)^{\frac{1}{n+1}}} \right) \end{aligned}$$

#### Critical current

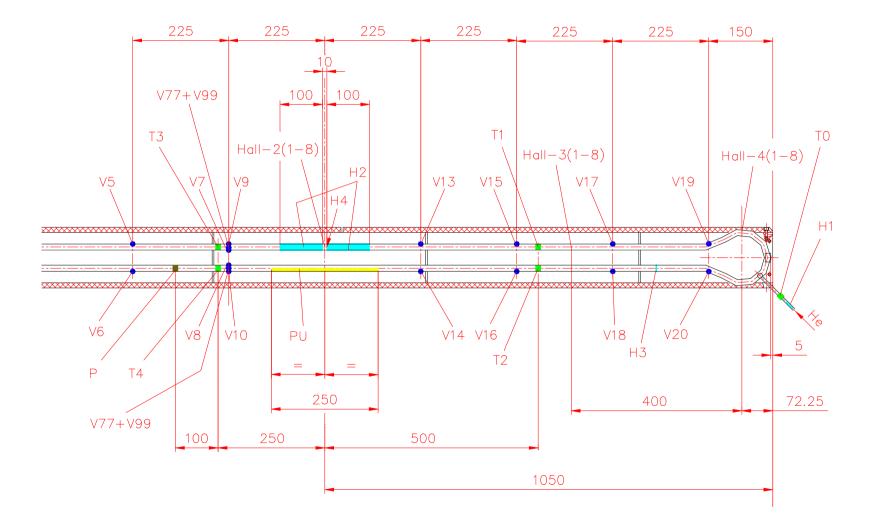
$$I_q = \frac{nI_{c0}}{n+1} \left(\frac{\Phi}{n}\right)^{\frac{1}{n+1}} \left(1 - \frac{T_{op}}{T_c}\right)$$

$$T_{q\_cond} = \frac{T_c}{n+1} \left( 1 + n \frac{T_{op}}{T_c} \right)$$

$$E_q = E_c \left(\frac{\Phi}{n}\right)^{\frac{n}{n+1}} \sim \frac{hp_w T_c}{nI_{c0}} \qquad \text{Independent of current!!}$$



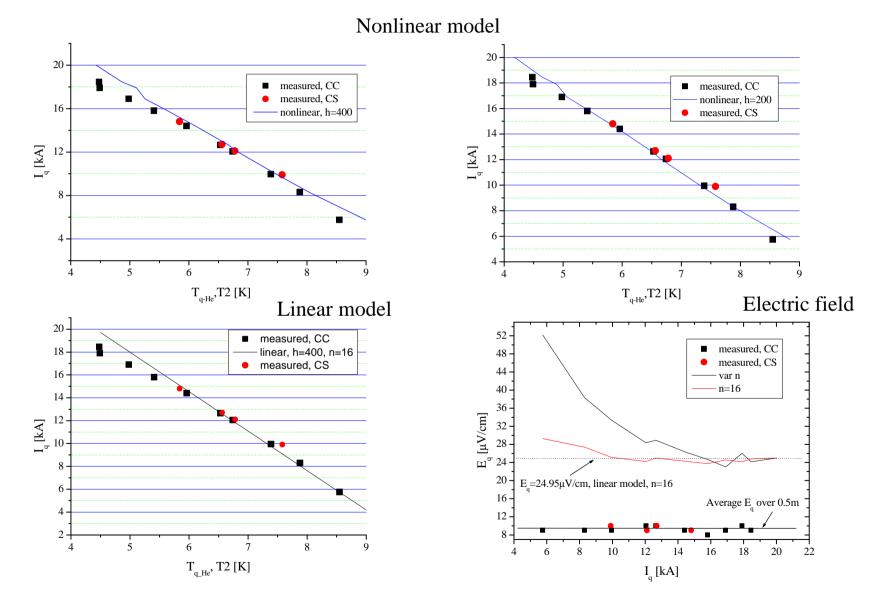
#### **Condopt** sample instrumentation





Condopt,B=10T

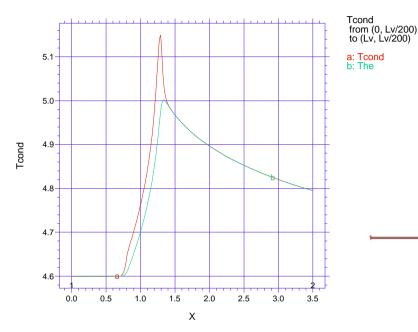
## **Theory vs. Experiment**



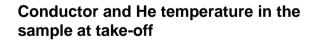


## **1D simulation**

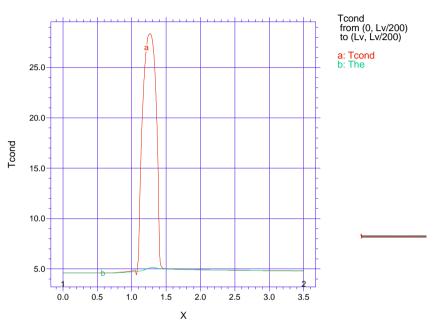
Ic-simulation



Ic-simulation: Cycle=247 Time= 235.00 dt= 0.2063 p2 Nodes=337 Cells=120 RMS Err= 1.3e-5 Integral(a)= 16.82361 Integral(b)= 16.77546



Ic-simulation



Ic-simulation: Cycle=335 Time= 235.17 dt= 5.2853e-5 p2 Nodes=2488 Cells=1163 RMS Err= 3.2 Integral(a)= 22.12752 Integral(b)= 16.82122

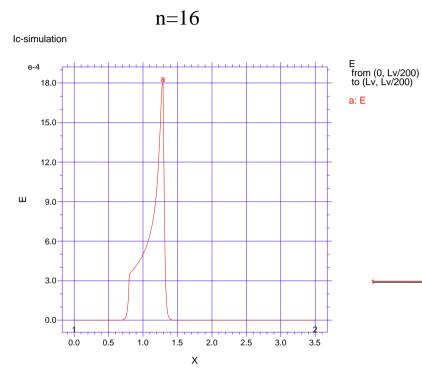
Conductor and He temperature in the sample after take-off (170ms)

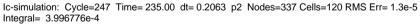
h=400W/m<sup>2</sup>K (from Tcs simulations in SECRETS), T<sub>he</sub> inlet=4.6K, =3g/s, n=16

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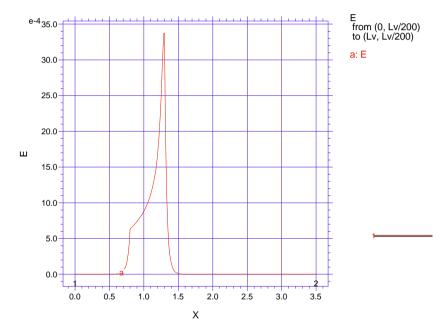


### **1D electric field**





Ic-simulation



n=8

Ic-simulation: Cycle=247 Time= 237.00 dt= 0.2730 p2 Nodes=337 Cells=120 RMS Err= 9.2e-6 Integral= 7.622767e-4

Electric field in the sample at take-off



# Conclusions

•The method presented shows that it is possible to obtain a good estimate of the quench point parameters of CIC conductors

•This has been done by considering the thermal equilibrium of a conductor with power-law VAC and not assuming ab initio that the conductor and He have the same temperature.

•Calculation with fully non linear model show a good agreement with the experimental results

•For a linear dependence of the critical current on temperature, a fully analytic model can be developed.

•Usefull formulas for the calculation of the quench point parameters in the frame of the linear model are given and it was shown that they can be expressed with the help of a new nondimensional group called ,,quench number"

•The calculation with the linear model show also a good agreement with the experimental results.

•In the frame of the linear model it was shown that the electrical field at quench is independent on current. Experimental data can be used to asses the value of the heat exchange coefficient from DC experiments and offer an alternative to the assessment through stability.